### **Supporting Information for**

# Carbon-metal versus Metal-metal Synergistic Mechanism of Ethylene Electrooxidation via Electrolysis Water on TM<sub>2</sub>N<sub>6</sub> sites in Graphene

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#### Table of contents

(Total Number of Pages: 24, Total Number of Figures: 18, Total Number of Tables: 3)

<b>Table S1.</b> Free energy difference ( $\Delta G$ , eV) of O atom adsorbed at	Page S4		
difference sites for 19 $TM_2N_6$ (a) graphenes, the "0 eV" represents the	U		
most stable O adsorption site, and "-" represents no corresponding			
configurations obtained during their optimization.			
Table S2. Total Gibbs free energy changes of ethylene oxidation	Page S5		
reaction initiated by stable *O intermediates to AA and EO on various	-		
$TM_2N_6@$ graphenes.			
<b>Table S3.</b> Gibbs free energy difference ( $\Delta G$ , eV) of OH adsorbed at	Page S6		
difference sites on 12 TM <sub>2</sub> N <sub>6</sub> @graphenes, the "0 eV" represents the	-		
most stable OH adsorption site, and "-" represents no corresponding			
configurations obtained during their optimization.			
<b>Fig. S1</b> Top and side views of various homonuclear TM <sub>2</sub> N <sub>6</sub> @graphene	Page S7		
DMACs with distances between two metal atoms in angstroms (Å).	-		
Fig. S2 Top and side views of O atom absorbed at the site-1 on various	Page S8		
$TM_2N_6@$ graphenes.	-		
Fig. S3 Top and side views of O atom absorbed at site-2 on various	Page S9		
$TM_2N_6@$ graphenes.			
Fig. S4 Top and side views of O atom absorbed at site-3 on various	Page S10		
$TM_2N_6@$ graphenes.			
Fig. S5 Top and side views of O atom absorbed at site-4 on various	Page S11		
$TM_2N_6@$ graphenes.			
Fig. S6 Top and side views of OH absorbed at site-1 on various	Page S12		
$TM_2N_6@$ graphenes.			
Fig. S7 Top and side views of OH absorbed at site-2 on various	Page S13		
$TM_2N_6@$ graphenes.			
Fig. S8 Top and side views of OH absorbed at site-4 on various	Page S14		
$TM_2N_6@$ graphenes.			
Fig. S9 Top and side views of OOH absorbed on various	Page S15		
$TM_2N_6@$ graphenes.			
Fig. S10 Top and side views of OO absorbed on various	Page S16		
$TM_2N_6@graphenes.$			
Fig. S11 Gibbs free energy change diagrams for ethylene electro-	Page S17		
oxidation on Co <sub>2</sub> N <sub>6</sub> @graphenes at the lowest applied potential to			
generate *O intermediates at pH=0.			
Fig. S12 Top and side views of acetaldehyde absorbed on various	Page S18		
$TM_2N_6@$ graphenes.			
Fig. S13 Top and side views of ethylene oxide absorbed on various	Page S19		
$TM_2N_6@$ graphenes.			
Fig. S14 Kinetic energy barriers and transition state structures of AA			
and EO generation through C-TM mechanism on Co <sub>2</sub> N <sub>6</sub> @graphenes.			

Fig. S15 Projected density of states (PDOS) of the d orbitals of the two		
metals in $TM_2N_6$ @graphenes.		
Fig. 16 Linear relationship between d-band center of metals in	Page S22	
TM <sub>2</sub> N <sub>6</sub> @graphenes and energy difference of the most stable OH		
adsorption sites between metal and C sites.		
Fig. S17 Evolution of the total energy of 9 TM <sub>2</sub> N <sub>6</sub> @graphene at 300 K,		
and the total times duration 10 ps. Snapshots of structures at the end of		
AIMD simulations are also shown.		
Fig. S18 Evolution of the total energy of 9 $TM_2N_6$ @graphene at 500 K,		
and the total times duration 10 ps. Snapshots of structures at the end of		
AIMD simulations are also shown.		

metal	site-1	site-2	site-3	site-4
TiTi	0	_	3.42	_
VV	0.17	0	4.21	—
CrCr	0.77	0	3.28	3.23
MnMn	0.43	0	1.74	1.61
FeFe	0	0.03	0.63	0.61
CoCo	0.17	0.17	0.17	0
NiNi	0.90	0.77	0.13	0
CuCu	0.93	0.88	0.09	0
ZnZn	0	_	0.43	0.39
МоМо	0.76	0	3.87	_
RuRu	0.44	0	1.23	1.20
RhRh	1.11	0.50	0.23	0
PdPd	1.20	0.84	0.09	0
ТаТа	0	0.18	4.39	_
WW	0.73	0	4.11	_
ReRe	0.92	0	2.65	2.61
OsOs	1.56	0	1.48	1.43
IrIr		0.27	0.30	0
PtPt	1.44	0.62	0.20	0

**Table S1.** Free energy difference ( $\Delta G$ , eV) of O atom adsorbed at difference sites for 19 TM<sub>2</sub>N<sub>6</sub>@graphenes, the "0 eV" represents the most stable O adsorption site, and "-" represents no corresponding configurations obtained during their optimization.

metal type	Ti	V	Cr	Mn	Fe
$\Delta G_{AA} \left( eV \right)$	0.88	2.25	0.78	-0.98	-2.18
$\Delta G_{EO} \left( eV \right)$	2.09	3.46	1.99	0.23	-0.97
metal type	Co	Ni	Cu	Zn	Мо
$\Delta G_{AA} \left( eV \right)$	-2.80	-2.95	-2.65	-2.01	1.67
$\Delta G_{EO} \left( eV \right)$	-1.60	-1.74	-1.44	-0.80	2.88
metal type	Ru	Rh	Pd	Ta	W
$\Delta G_{AA} (eV)$	-1.44	-1.49	-2.58	2.12	1.68
$\Delta G_{EO} \left( eV \right)$	-0.23	-2.70	-1.37	3.33	2.83
metal type	Re	Os	Ir	Pt	
$\Delta G_{AA} \left( eV \right)$	0.32	-1.08	-2.51	-2.32	
$\Delta G_{EO} \left( eV \right)$	1.53	0.13	-1.31	-1.11	

**Table S2.** Total Gibbs free energy changes of ethylene oxidation reaction initiated bystable \*O intermediates to AA and EO on various  $TM_2N_6@$  graphenes.

metal	site-1	site-2	site-3	site-4
MnMn	_	0		1.30
FeFe	0.09	0	—	0.66
CoCo	_	0		0.48
NiNi	_	0		0.19
CuCu	0.02	0.02	_	0
ZnZn	0.09	0		1.25
RuRu	1.12	0		1.21
RhRh	_	0	_	0.18
PdPd	_	0.06	_	0
OsOs	1.54	0	_	1.29
IrIr	_	0	_	0.07
PtPt	_	0.16	_	0

12 TM<sub>2</sub>N<sub>6</sub>@graphenes, the "0 eV" represents the most stable OH adsorption site, and "-" represents no corresponding configurations obtained during their optimization.

**Table S3.** Gibbs free energy difference ( $\Delta G$ , eV) of OH adsorbed at difference sites on



Fig. S1 Top and side views of various homonuclear  $TM_2N_6$ @graphene DMACs with distances between two metal atoms in angstroms (Å).



Fig. S2 Top and side views of O atom absorbed at site-1 on various  $TM_2N_6$ @graphenes.



Fig. S3 Top and side views of O atom absorbed at site-2 on various  $TM_2N_6@$  graphenes.



Fig. S4 Top and side views of O atom absorbed at site-3 on various  $TM_2N_6@$  graphenes.



Fig. S5 Top and side views of O atom absorbed at site-4 on various  $TM_2N_6@$  graphenes.



Fig. S6 Top and side views of OH absorbed at site-1 on various  $TM_2N_6@$  graphenes.



Fig. S7 Top and side views of OH absorbed at site-2 on various  $TM_2N_6@$  graphenes.



Fig. S8 Top and side views of OH absorbed at site-4 on various  $TM_2N_6@$  graphenes.



Fig. S9 Top and side views of OOH absorbed on various  $TM_2N_6@$  graphenes.



Fig. S10 Top and side views of OO absorbed on various  $TM_2N_6@$  graphenes.



## **Reaction Path**

Fig. S11 Gibbs free energy change diagrams for ethylene electro-oxidation on  $Co_2N_6$ @graphenes at the lowest applied potential to generate \*O intermediates at pH=0.



Fig. S12 Top and side views of acetaldehyde absorbed on various  $TM_2N_6@$  graphenes.



Fig. S13 Top and side views of ethylene oxide absorbed on various  $TM_2N_6@$  graphenes.



# **Reaction coordinate**

Fig. S14 Kinetic energy barriers and transition state structures of AA and EO generation through C-TM mechanism on  $Co_2N_6$ @graphenes.



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 $TM_2N_6@graphenes.\\$ 



Fig. S16 Linear relationship between d-band center of metals in  $TM_2N_6$ @graphenes and energy difference of the most stable OH adsorption sites between metal and C sites.



Fig. S17 Evolution of the total energy of 9  $TM_2N_6$ @graphene at 300 K, and the total times duration 10 ps. Snapshots of structures at the end of AIMD simulations are also shown.



Fig. S18 Evolution of the total energy of 9  $TM_2N_6$ @graphene at 500 K, and the total times duration 10 ps. Snapshots of structures at the end of AIMD simulations are also shown.